IN THE CLAIMS:

Claims 1-21. Canceled.

22. (Currently Amended) An apparatus for surface treatment comprising:

a processing vessel in which an object to be processed is placed;

[[means]] a CIF₃ supplier for supplying CIF₃ gas into the processing vessel;

[[means]] <u>a promoter</u> for promoting adhesion of CIF₃ gas to <u>a surface of</u> the object to be processed;

an evacuator for evacuating CIF₃ gas from the processing vessel; and

[[means]] an activator for activating CIF₃ gas supplied in the processing vessel adhered to the surface of the object so as to remove an oxide formed on the surface of the object by using the CIF₃ adhered to the surface of the object.

- 23. (Previously Presented) An apparatus for surface treatment according to claim 22, further comprising a mount located in the processing vessel for setting the object to be processed thereon.
- 24. (Currently Amended) An apparatus for surface treatment according to claim 23, wherein the means for promoting adhesion of the CIF₃ gas to the object to be processed promoter is provided in the mount, the means for promoting adhesion thereby cooling the object to be processed on the mount.

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25. (Currently Amended) An apparatus for surface treatment according to claim 24, wherein the means for activating the CIF₃ gas activator heats the object to be processed in a heating position at a distance from an object setting position of the object on the mount.

26. (Currently Amended) An apparatus for surface treatment according to claim 25, further comprising means for elevating and lowering an elevator for moving the object to be processed up and down between the object setting position and the heating position.

27. (Currently Amended) A cluster device comprising[:] the apparatus for surface treatment according to claim [[21]] <u>22</u>, <u>and</u> further comprising:

a transport chamber for maintaining a non-reactive atmosphere therein and for transporting an object to be processed in the non-reactive atmosphere to and from the apparatus for surface treatment; and

at least one processing apparatus for transporting the object to be processed to and from the transport chamber.

28. (Original) The cluster device according to claim 27, wherein the apparatus for surface treatment is a metal wiring formation chamber for making metal wiring on the object to be processed.

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- 29. Canceled.
- 30. Canceled
- 31. Canceled.
- 32. Canceled.
- 33. (New) A cluster device comprising:

a transport chamber for maintaining a non-reactive atmosphere therein and for transporting an object to be processed in the non-reactive atmosphere to and from an apparatus for surface treatment;

at least one processing apparatus for transporting the object to be processed to and from the transport chamber; and

an apparatus for surface treatment including

- a processing vessel in which an object to be processed is placed;
- a CIF₃ supplier for supplying CIF₃ gas into the processing vessel;

an activator for activating the CIF₃ gas supplied in the processing vessel; and a reducer supplier for supplying a reducing gas into the processing vessel.

34. (New) A cluster device according to claim 33, wherein the apparatus for surface treatment is a metal wiring formation chamber for making metal wiring on the object to be processed.

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35. (New) An apparatus for surface treatment according to claim 22, further comprising a reducer supplier for supplying a reducing gas into the processing vessel.

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